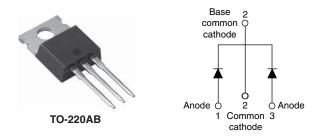


Vishay Semiconductors





PRODUCT SUMMARY					
Package	TO-220AB				
I _{F(AV)}	2 x 30 A				
V _R	30 V				
V_F at I_F	0.44 V				
I _{RM} max.	350 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Common cathode				
E _{AS}	13 mJ				

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- · High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- RoHS COMPLIANT HALOGEN FREE
- · Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform (per device)	60	A			
V _{RRM}		30	V			
I _{FRM}	$T_{\rm C} = 120 \ ^{\circ}{\rm C}$ (per leg)	60	Α			
I _{FSM}	t _p = 5 μs sine	1500	A			
V _F	30 A _{pk} , T _J = 125 °C	0.44	V			
TJ	Range	- 65 to 150	°C			

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-62CTQ030PbF	VS-62CTQ030-N3	UNITS
Maximum DC reverse voltage	V _R	30	30	V
Maximum working peak reverse voltage	V _{RWM}		30	v

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	PARAMETER		TEST COND	ITIONS	VALUES	UNITS	
Maximum average per leg			50 % duty cycle at $T_{e} = 120$ %	rootangular wayoform	30		
forward current	per device	IF(AV)	$I_{F(AV)}$ 50 % duty cycle at T_C = 120 °C, rectangular waveform		60		
Peak repetitive forward current per leg		I _{FRM}	Rated V _R , square wave, 20 kHz, T_C = 127 °C		60	А	
Maximum peak one cycle non-i	Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	1500		
surge current per leg		IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	300		
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 2.9 mH		13	mJ	
Repetitive avalanche current pe	er leg	I _{AR}	Current decaying linearly to zero Frequency limited by T_J maxim		3	А	

Revision: 29-Aug-11

1



Vishay Semiconductors

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	TYP.	MAX.	UNITS	
		30 A	T.I = 25 °C	0.46	0.5		
Maximum forward voltage drop	V _{FM} ⁽¹⁾	60 A	1j=25 0	0.56	0.6	V	
	VFM (1)	30 A	T 105 %O	0.39	0.44		
		60 A	T _J = 125 °C	0.54	0.59		
Maximum instantaneous reverse current	I _{RM}	$T_J = 25 \ ^\circ C$	Rated DC voltage	0.4	2.5	mA	
		T _J = 125 °C	Haled DC vollage	180	350	IIIA	
Maximum junction capacitance	CT	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 °C		30	00	pF	
Typical series inductance	L _S	Measured from top of terminal to mounting plane		8	.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R 10 000				V/µs	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,\,duty\,cycle$ < 2 $\,\%$

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperatur	e range	TJ		- 65 to 150	о°С	
Maximum storage temperatur	e range	T _{Stg}		- 65 to 175	-0	
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	1.2	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	0/10	
Approximate weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque minimum maximum			New Jule Sector differences	6 (5)	kgf ⋅ cm	
		Non-lubricated threads		12 (10)	(lbf ⋅ in)	
Marking device			Case style TO-220AB	62CT	Q030	



Vishay Semiconductors

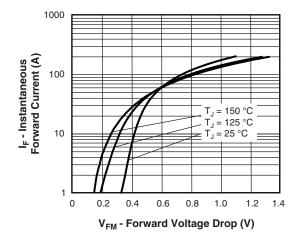


Fig. 1 - Maximum Forward Voltage Drop Characteristics

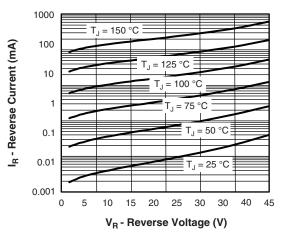


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

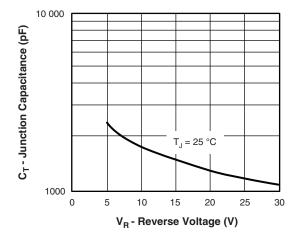
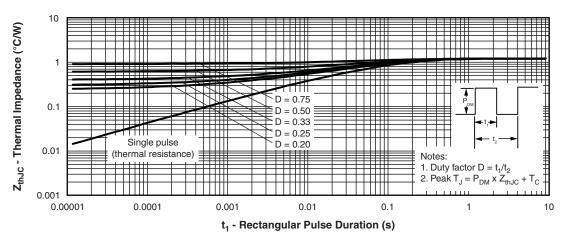


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



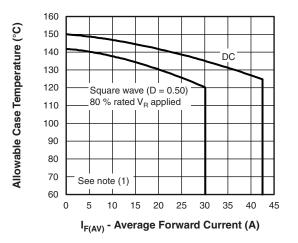


Revision: 29-Aug-11 3 Document Number: 94242 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFI Downloaded From Oneyac.com w.vishay.com/doc?91000



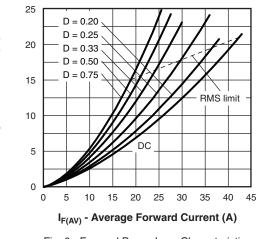
Average Power Loss (W)

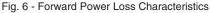
Vishay Semiconductors



www.vishay.com

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current





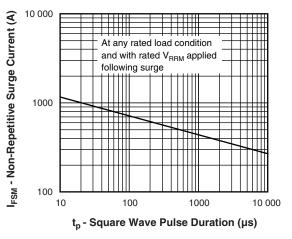


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note



Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code	VS-	62	С	т	Q	030	PbF
	1	2	3	4	5	6	7
1	-	Vishay	Semico	onductor	s produ	ct	
2	2 - Current rating (60 = 60 A)						
3	-	Circuit	configu	ration			
		C = Co	mmon d	cathode			
4	-	Packag	je				
		T = TO	-220				
5	-	Schottky "Q" series					
6	-	Voltage rating (030 = 30 V)					
7	-	Environmental digit					
		• PbF	= Lead	(Pb)-fre	e and R	oHS co	mpliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-62CTQ030PbF	50	1000	Antistatic plastic tube			
VS-62CTQ030-N3	50	1000	Antistatic plastic tube			

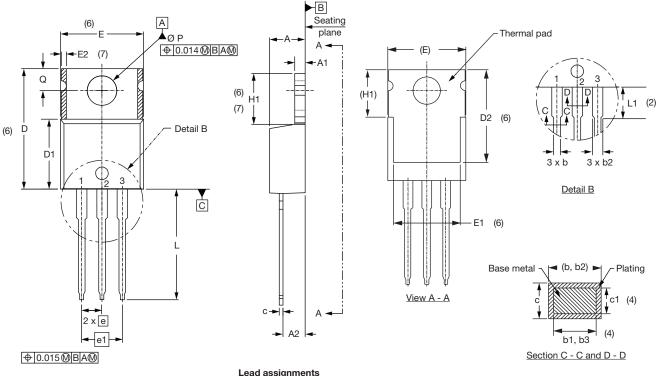
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95222					
Part marking information	TO-220AB PbF	www.vishay.com/doc?95225			
	TO-220AB -N3	www.vishay.com/doc?95028			
SPICE model		www.vishay.com/doc?95185			

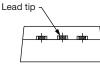


Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches





Leau	l as:	sign	me	ΠU
		-		

Diodes 1. - Anode/open

2. - Cathode 3. - Anode

	MILLIN	IETERS	INC	HES	
SYMBOL			_	-	NOTES
	MIN.	MAX.	MIN.	MAX.	
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- ⁽³⁾ Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed $0.127 \text{ mm} (0.005^{\circ})$ per side. These dimensions are measured at the outermost extremes of the plastic body
- $^{\left(4\right) }$ Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1

SYMBOL	MILLIMETERS		INC	NOTES	
STWIDUL	MIN.	MAX.	MIN.	MAX.	NUTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	

Conforms to JEDEC outline TO-220AB

- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- Outline conforms to JEDEC TO-220, except A2 (maximum) and (8) D2 (minimum) where dimensions are derived from the actual package outline

For technical questions within your region, please contact one of the following: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)